

1 **Supplementary information**

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3 Discovery of temperature-induced stability reversal in perovskites using high-throughput robotic
4 learning

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Supplementary methods

Device fabrication

First, ITO substrates were sonicated in acetone and isopropanol for 30 minutes and 60 minutes, respectively. SnO₂-PEIE solution (80 μL) was spin-coated on ITO substrates at 3500 rpm for 30 seconds and then annealed at 150°C for 10 minutes in ambient air. Then, 80 μL of PCBM:PMMA solution was spin-coated on a SnO₂/PEIE layer at 2000 rpm for 30 seconds and then annealed at 150°C for 10 minutes in a glovebox. MnSO₄ modification was achieved by sequentially spin-coating MnAc₂ and (NH₄)₂SO₄ solutions at 2000 rpm/30 s and annealing each layer at 150°C for 10 minutes in a N₂-filled glovebox. Perovskite solution (1.2 M, 80 μL) was spin-coated on the MnSO₄-modified substrate by using the following parameters: 200 rpm for 2 seconds, 2000 rpm for 2 seconds, and 5000 rpm for 40 seconds (a=3 seconds). Then, 180 μL of chlorobenzene was dropped on the film at 20 seconds, followed by annealing at 110°C for 10 minutes and 150°C for 5 minutes. The as-prepared perovskite film was then spin-coated by PDCBT as a hole transporting layer at 2000 rpm for 40 seconds and annealed at 90°C for 5 minutes. Finally, 100 μL of Ta-WO_x was coated on PDCBT at 2000 rpm for 30 seconds and annealed at 75°C in ambient air. A 100-nm-thick Au electrode was deposited through a shadow mask *via* thermal evaporation. For the devices used in the stability tests, a 200 nm Au layer was deposited.

33 ***Film characterization***

34 High-throughput PL/Abs. characterization was performed with TECAN infinite 200Pro. The PL
35 signal was collected from the top side of the perovskite film from 650 nm to 850 nm with a 4 nm
36 step. The absorbance signal was collected from 720 nm to 850 nm with a 2 nm step. Scanning
37 electron microscopy (SEM) images were obtained by using a 10 kV acceleration voltage with an
38 FEI Helios Nanolab 660 setup. X-ray diffraction analysis was performed with Bragg-Brentano
39 geometry using a Panalytical X'pert powder diffractometer with filtered Cu-K α radiation and an
40 X'Celerator solid-state stripe detector.

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Supplementary Note 1

A simplified model for thermodynamic control vs. kinetic control

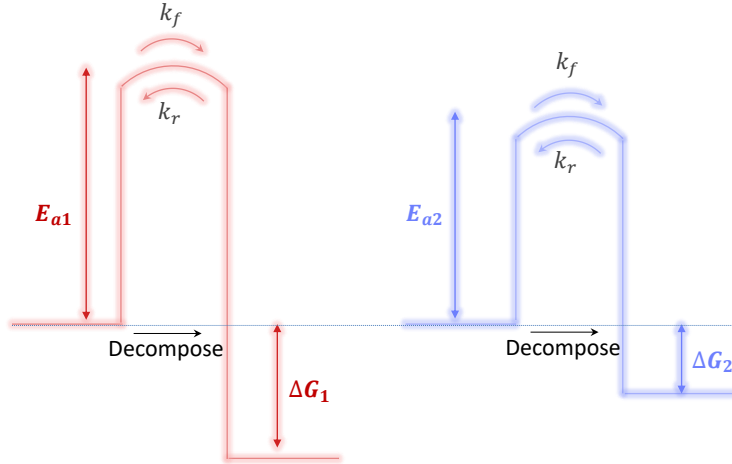


Fig. N1 Schematic of the potential diagram for the decomposition of two materials: one has both a higher activation energy (E_a) and dissociation energy (ΔG) than the other.

The potential decomposition rate is mainly influenced by two factors: 1. the relative stability of the decomposition product, which is associated with ΔG ; and 2. the energy barrier of the decomposition, which is associated with E_a . The following equations provide a basis for understanding the transformation from thermodynamic to kinetic control.

Decomposition rate Δk_1 of reaction 1:

$$\begin{aligned} \Delta k_1 &= k_{f1} - k_{r1} \\ &= \exp\left(-\frac{E_{a1}}{k_B T}\right) \times (k_{f0} - k_{r0} \times \exp\left(-\frac{\Delta G_1}{k_B T}\right)) \\ &= k_{01}^{eff} \exp\left(-\frac{E_{a1}}{k_B T}\right) \end{aligned} \quad (1)$$

Decomposition rate Δk_2 of reaction 2:

$$\begin{aligned}
57 \quad \Delta k_2 &= k_{f1} - k_{r1} \\
58 \quad &= \exp\left(-\frac{E_{a2}}{k_B T}\right) \times (k_{f0} - k_{r0} \times \exp\left(-\frac{\Delta G_2}{k_B T}\right)) \\
59 \quad &= k_{02}^{eff} \exp\left(-\frac{E_{a2}}{k_B T}\right) \quad (2)
\end{aligned}$$

60 The relative rate r is derived as:

$$\begin{aligned}
61 \quad r &= \frac{\Delta k_1}{\Delta k_2} \\
62 \quad &= \frac{k_{01}^{eff} \exp\left(-\frac{E_{a1}}{k_B T}\right)}{k_{02}^{eff} \exp\left(-\frac{E_{a2}}{k_B T}\right)} \\
63 \quad &= \exp\left(-\frac{\Delta E}{k_B T}\right) \times \left(\frac{k_{01}^{eff}}{k_{02}^{eff}}\right) \quad (3)
\end{aligned}$$

64 where $k_{f1/2}$ and $k_{r1/2}$ indicate the forward and backward reaction rates, respectively. k_{01}^{eff} and
65 k_{02}^{eff} denote the effective pre-exponential factor in the Arrhenius equations (1) and (2),
66 respectively. $\Delta E = E_{a1} - E_{a2}$. Reaction 1 will have a lower decomposition rate than reaction 2
67 if $r < 1$.

68 Considering the volatile nature of MAI/FAI, the backward reaction constant k_{r0} is much
69 lower than k_{f0} , and the right hand sides of equations (1), (2), and (3) are positive in the
70 decomposition process.

71 At temperature falls, k_{01}^{eff} and k_{02}^{eff} become constant, and $\exp\left(-\frac{\Delta E}{k_B T}\right)$ dominates the
72 decomposition rate in equation (3). In this case, the decomposition is kinetically controlled,
73 which is dictated by the relative activation energy. Since $\Delta E > 0$, the first material will have a
74 larger decomposition rate than the second one below a critical temperature.

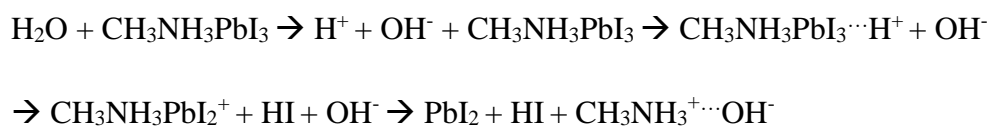
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Supplementary Note 2

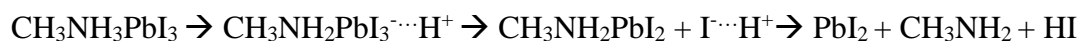
Possible origins of the different pre-exponential factors

The decomposition process from perovskite to PbI_2 is a multistep process. The protonation of surface iodide is the first step, leading to an iodide vacancy. We speculate that the frequency of protonation plays a key role in determining the reaction constant K_0 in the Arrhenius equation, in addition to ΔG . The protons can originate from water molecules in the environment or MA^+/FA^+ in the perovskite lattice.

With H_2O , the hydrolysis rate at the MAPbI_3 surface is higher than that at the FAPbI_3 surface, leading to a larger K_0 for MAPbI_3 or MA-containing perovskites:



Without H_2O , the higher deprotonation/migration rate of MA^+ than FA^+ in perovskite leads to a larger K_0 for MAPbI_3 or MA-containing perovskites:



Extended figure/table legends



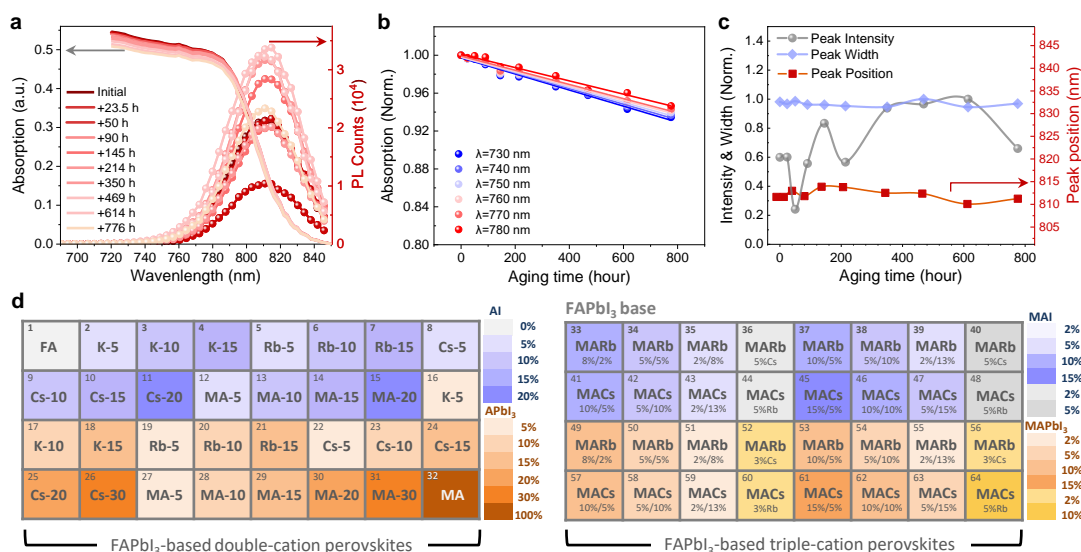
Supplementary Fig. 1. Three climate chambers for the thermal stability test under dark conditions.

115 **Supplementary Table 1.** A summary of previous studies on the film stability of mixed-cation perovskites.

Supplementary Table 1. Summary of studies on film stability of perovskites (MA⁺: CH₃NH₃⁺; FA⁺: NH₂CHNH₂⁺)

Aging condition	Composition and processing	Conclusion	Reference
130°C-dark in air (humidity not indicated)	MAPbI ₃ , Cs _{0.05} (MAFA) _{0.95} PbI ₃ , MAPbI ₃ , Rb _{0.05} Cs _{0.05} (MAFA) _{0.9} PbI ₃ , FAPbI ₃ , Rb _{0.05} FA _{0.95} PbI ₃ , Cs _{0.1} FA _{0.9} PbI ₃ , Rb ₅ Cs ₁₀ FAPbI ₃ films <i>via</i> 1-step spin-coating	Organic MA deteriorates stability	Science 362, 449–453 (2018)
130°C-dark in air (humidity not indicated)	Cs _x (MA _{0.17} FA _{0.83}) _(100-x) Pb(I _{0.83} Br _{0.17}) ₃ (x=0/10) films <i>via</i> 1-step spin-coating	Inorganic Cs improves stability	Energy Environ. Sci. 9, 1989-199 (2016)
140°C-dark in air (humidity: 40%RH)	Cs _x (MA _{0.17} FA _{0.83}) _(100-x) Pb(I _{0.97} Br _{0.03}) ₃ (x=0/1/2/3) films <i>via</i> 2-step spin-coating	Inorganic Cs improves stability	Nat. Commun. 9, 1607 (2018)
130°C-dark in N ₂	FA _{0.83} Cs _{0.17} Pb(I _{0.6} Br _{0.4}) ₃ , MAPb(I _{0.6} Br _{0.4}) ₃ films <i>via</i> 1-step spin-coating	Higher stability of CsFA-based perovskites than MA	Science 351,151–155 (2016)
150°C-dark in N ₂	MAPbI ₃ , FAPbI ₃ films <i>via</i> 1-step spin-coating	MA deteriorates stability	Energy Environ. Sci. 7, 982-988 (2014)
150°C-dark in air	MAPbI ₃ , FAPbI ₃ films <i>via</i> 1-step spin-coating	MA deteriorates stability	Nat. Nanotechnol 10, 391-402 (2015)

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Supplementary Fig. 2. **a** The absorption/PL spectra *versus* ageing time on the timescale of hours for FAPbI₃ films fabricated through the drop-cast method under 85 °C and 10% RH. **b** The extracted absorbance values at six different wavelengths (from 730 nm to 780 nm) as a function of ageing time. **c** The PL intensity, peak position and full width at half maximum as a function of ageing time. These values were obtained by Gaussian fitting. The large perturbation of PL intensity over time is mainly caused by the small change inside the PL system during the long-term operation period. **d** Compositions of the mixed-cation perovskites studied in this work. The serial number at the top-left corner represents the different cation combinations, while the background colour indicates the doping concentration in the FAPbI₃ matrix. The left table mainly summarizes double-cation perovskites, and the right table summarizes triple-cation perovskites. For each combinatorial cation, both standard-stoichiometric and over-stoichiometric samples were prepared, and these are marked by orange and blue in the table, respectively.

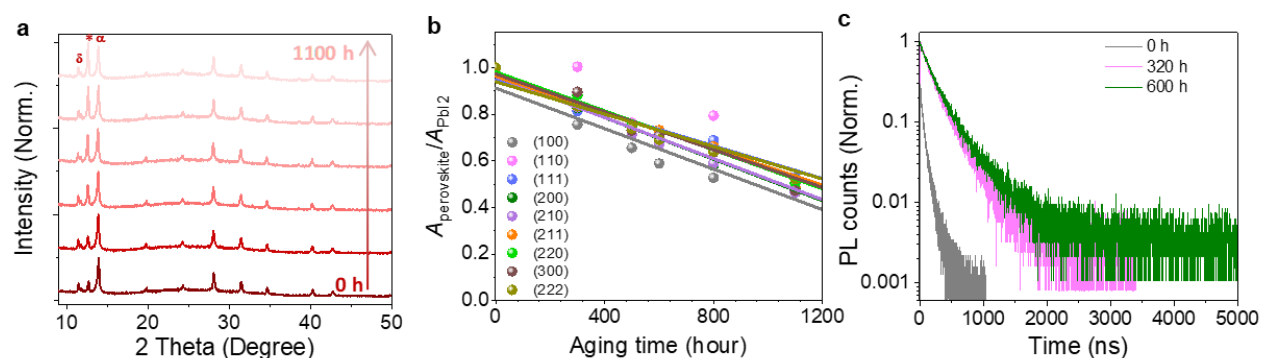
141 **Supplementary Table 2.** A summary of the compositions of the 64 materials used in this study and their
 142 preparations.

Supplementary Table 2. Summary of the 64 composites and their corresponding recipes.

Serial Number	Target Composition	Recipe	Serial Number	Target Composition	Recipe
No.1	FAPbI ₃	200 µL FAPbI ₃	No.33	FAPbI ₃ + 2%RbI + 8%MAI	5 µL RbI +15 µL MAI + 200 µL FAPbI ₃
No.2	FAPbI ₃ +5%KI	10 µL KI + 200 µL FAPbI ₃	No.34	FAPbI ₃ +5%RbI+5%MAI	10 µL RbI +10 µL MAI + 200 µL FAPbI ₃
No.3	FAPbI ₃ +10%KI	20 µL KI + 200 µL FAPbI ₃	No.35	FAPbI ₃ +8%RbI+2%MAI	16 µL RbI + 4 µL MAI + 200 µL FAPbI ₃
No.4	FAPbI ₃ +15%KI	30 µL KI + 200 µL FAPbI ₃	No.36	FAPbI ₃ +5%RbI+3%CsI+2%MAI	10 µL RbI + 6 µL CsI + 4 µL MAI + 200 µL FAPbI ₃
No.5	FAPbI ₃ +5%RbI	10 µL RbI + 200 µL FAPbI ₃	No.37	FAPbI ₃ +5%RbI+10%MAI	10 µL RbI + 20 µL MAI + 200 µL FAPbI ₃
No.6	FAPbI ₃ +10%RbI	20 µL RbI + 200 µL FAPbI ₃	No.38	FAPbI ₃ +10%RbI+5%MAI	20 µL RbI + 10 µL MAI + 200 µL FAPbI ₃
No.7	FAPbI ₃ +15%RbI	30 µL RbI + 200 µL FAPbI ₃	No.39	FAPbI ₃ +12.5%RbI+2.5%MAI	25 µL RbI + 5 µL MAI + 200 µL FAPbI ₃
No.8	FAPbI ₃ +5%CsI	10 µL CsI + 200 µL FAPbI ₃	No.40	FAPbI ₃ +5%RbI+5%CsI+5%MAI	10 µL RbI + 10 µL CsI + 10 µL MAI + 200 µL FAPbI ₃
No.9	FAPbI ₃ +10%CsI	20 µL CsI + 200 µL FAPbI ₃	No.41	FAPbI ₃ +5%CsI+10%MAI	10 µL CsI + 20 µL MAI + 200 µL FAPbI ₃
No.10	FAPbI ₃ +15%CsI	30 µL CsI + 200 µL FAPbI ₃	No.42	FAPbI ₃ +10%CsI+5%MAI	20 µL CsI + 10 µL MAI + 200 µL FAPbI ₃
No.11	FAPbI ₃ +20%CsI	40 µL CsI + 200 µL FAPbI ₃	No.43	FAPbI ₃ +13%CsI+2%MAI	26 µL CsI + 4 µL MAI + 200 µL FAPbI ₃
No.12	FAPbI ₃ +5%MAI	10 µL MAI + 200 µL FAPbI ₃	No.44	FAPbI ₃ +3%RbI+10%CsI+2%MAI	6 µL RbI + 20 µL CsI + 4 µL MAI + 200 µL FAPbI ₃
No.13	FAPbI ₃ +10%MAI	20 µL MAI + 200 µL FAPbI ₃	No.45	FAPbI ₃ +5%CsI+15%MAI	10 µL CsI + 30 µL MAI + 200 µL FAPbI ₃
No.14	FAPbI ₃ +15%MAI	30 µL MAI + 200 µL FAPbI ₃	No.46	FAPbI ₃ +10%CsI+10%MAI	20 µL CsI + 20 µL MAI + 200 µL FAPbI ₃
No.15	FAPbI ₃ +20%MAI	40 µL MAI + 200 µL FAPbI ₃	No.47	FAPbI ₃ +15%RbI+5%MAI	30 µL CsI + 10 µL MAI + 200 µL FAPbI ₃

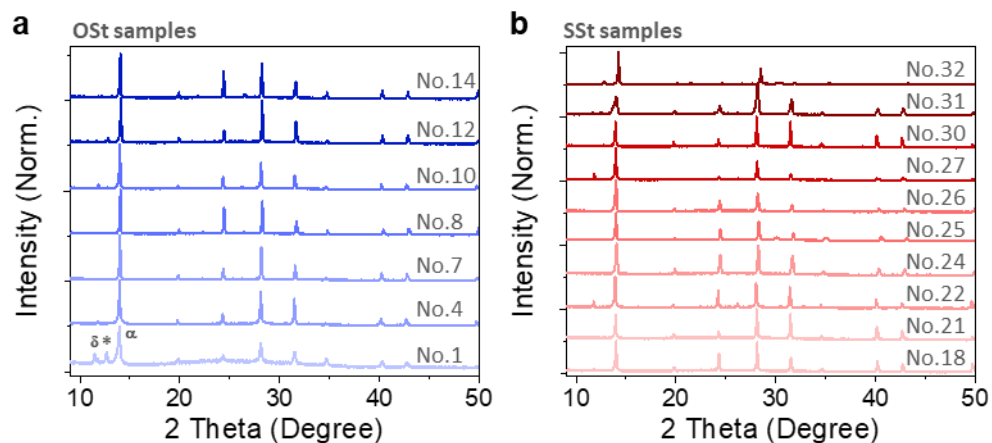
No.16	$(K_{0.05}FA_{0.95})PbI_3$	10 μ L KPbI ₃ + 190 μ L FAPbI ₃	No.48	FAPbI ₃ +5%RbI+10%CsI+5%MAI	10 μ L RbI + 20 μ L CsI+10 μ L MAI+ 200 μ L FAPbI ₃
No.17	$(K_{0.1}FA_{0.9})PbI_3$	20 μ L KPbI ₃ + 180 μ L FAPbI ₃	No.49	$(Rb_{0.02}MA_{0.08}FA_{0.9})PbI_3$	4 μ L MAPbI ₃ +16 μ L MAPbI ₃ + 180 μ L FAPbI ₃
No.18	$(K_{0.15}FA_{0.85})PbI_3$	30 μ L KPbI ₃ + 170 μ L FAPbI ₃	No.50	$(Rb_{0.05}MA_{0.05}FA_{0.9})PbI_3$	10 μ L RbPbI ₃ + 10 μ L MAPbI ₃ + 180 μ L FAPbI ₃
No.19	$(Rb_{0.05}FA_{0.95})PbI_3$	10 μ L RbPbI ₃ + 190 μ L FAPbI ₃	No.51	$(Rb_{0.08}MA_{0.02}FA_{0.9})PbI_3$	16 μ L RbPbI ₃ + 4 μ L MAPbI ₃ + 180 μ L FAPbI ₃
No.20	$(Rb_{0.1}FA_{0.9})PbI_3$	20 μ L RbPbI ₃ + 180 μ L FAPbI ₃	No.52	$(Rb_{0.05}Cs_{0.03}MA_{0.02}FA_{0.9})PbI_3$	10 μ L RbPbI ₃ + 6 μ L CsPbI ₃ + 4 μ L MAPbI ₃ + 180 μ L FAPbI ₃
No.21	$(Rb_{0.15}FA_{0.85})PbI_3$	30 μ L RbPbI ₃ + 170 μ L FAPbI ₃	No.53	$(Rb_{0.05}MA_{0.1}FA_{0.85})PbI_3$	10 μ L RbPbI ₃ + 20 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.22	$(Cs_{0.05}FA_{0.95})PbI_3$	10 μ L CsPbI ₃ + 190 μ L FAPbI ₃	No.54	$(Rb_{0.1}MA_{0.05}FA_{0.85})PbI_3$	20 μ L RbPbI ₃ + 10 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.23	$(Cs_{0.1}FA_{0.9})PbI_3$	20 μ L CsPbI ₃ + 180 μ L FAPbI ₃	No.55	$(Rb_{0.13}MA_{0.02}FA_{0.85})PbI_3$	25 μ L RbPbI ₃ + 5 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.24	$(Cs_{0.15}FA_{0.85})PbI_3$	30 μ L CsPbI ₃ + 170 μ L FAPbI ₃	No.56	$(Rb_{0.1}Cs_{0.03}MA_{0.02}FA_{0.85})PbI_3$	10 μ L RbPbI ₃ + 10 μ L CsPbI ₃ + 10 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.25	$(Cs_{0.2}FA_{0.8})PbI_3$	40 μ L CsPbI ₃ + 160 μ L FAPbI ₃	No.57	$(Cs_{0.05}MA_{0.1}FA_{0.85})PbI_3$	10 μ L CsPbI ₃ + 20 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.26	$(Cs_{0.3}FA_{0.7})PbI_3$	60 μ L CsPbI ₃ + 140 μ L FAPbI ₃	No.58	$(Cs_{0.1}MA_{0.05}FA_{0.85})PbI_3$	20 μ L CsPbI ₃ + 10 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.27	$(MA_{0.05}FA_{0.95})PbI_3$	10 μ L MAPbI ₃ + 190 μ L FAPbI ₃	No.59	$(Cs_{0.13}MA_{0.02}FA_{0.85})PbI_3$	26 μ L CsPbI ₃ + 4 μ L MAPbI ₃ + 170 μ L FAPbI ₃
No.28	$(MA_{0.1}FA_{0.9})PbI_3$	20 μ L MAPbI ₃ + 180 μ L FAPbI ₃	No.60	$(Rb_{0.03}Cs_{0.13}MA_{0.02}FA_{0.85})PbI_3$	6 μ L RbPbI ₃ + 20 μ L CsPbI ₃ + 4 μ L MAPbI ₃ + 170 μ L FAPbI ₃

No.29	$(MA_{0.15}FA_{0.85})PbI_3$	30 μ L MAPbI ₃ + 170 μ L FAPbI ₃	No.61	$(Cs_{0.05}MA_{0.15}FA_{0.8})PbI_3$	10 μ L CsPbI ₃ + 30 μ L MAPbI ₃ + 160 μ L FAPbI ₃
No.30	$(MA_{0.2}FA_{0.8})PbI_3$	40 μ L MAPbI ₃ + 160 μ L FAPbI ₃	No.62	$(Cs_{0.1}MA_{0.1}FA_{0.8})PbI_3$	20 μ L CsPbI ₃ + 20 μ L MAPbI ₃ + 160 μ L FAPbI ₃
No.31	$(MA_{0.3}FA_{0.7})PbI_3$	60 μ L MAPbI ₃ + 140 μ L FAPbI ₃	No.63	$(Cs_{0.15}MA_{0.05}FA_{0.8})PbI_3$	30 μ L CsPbI ₃ + 10 μ L MAPbI ₃ + 160 μ L FAPbI ₃
No.32	MAPbI ₃	200 μ L MAPbI ₃	No.64	$(Rb_{0.05}Cs_{0.05}MA_{0.1}FA_{0.8})PbI_3$	10 μ L RbPbI ₃ + 10 μ L CsPbI ₃ + 20 μ L MAPbI ₃ + 160 μ L FAPbI ₃



Supplementary Fig. 3. a The evolution of the XRD patterns at increasing ageing time for FAPbI₃ at 85°C. Symbol δ */ α indicates δ -FAPbI₃, decomposition product PbI₂, α -FAPbI₃ respectively. The decomposition process is manifested by more and more pronounced PbI₂ peak. **b** The ratio of α -FAPbI₃ perovskite to PbI₂ as a function of ageing time at 85°C. The areas under the (001) peaks at $2\theta=13.9^\circ$ and 12.6° are used to represent the amount of α -FAPbI₃ perovskite perovskite and PbI₂, respectively. A similar calculation was also applied to other facets of perovskite. Compared with the degradation rate obtained from absorbance, the faster degradation derived from the XRD peak area is mainly because we adopted the ratio value of perovskite to PbI₂, not the absolute value of perovskite, to exclude the intensity variation in *ex situ* measurements. **c** Time-resolved photoluminescence of FAPbI₃ after thermal ageing for over 900 hours at 85 °C.

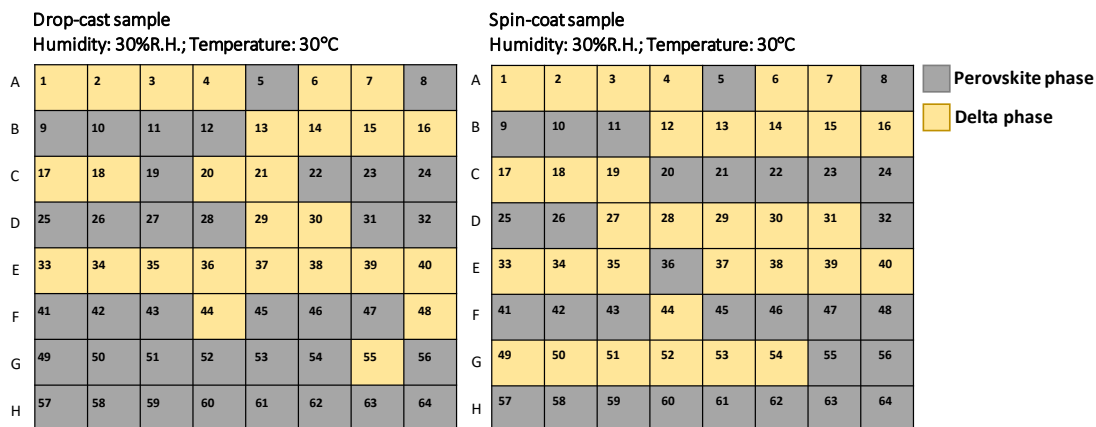
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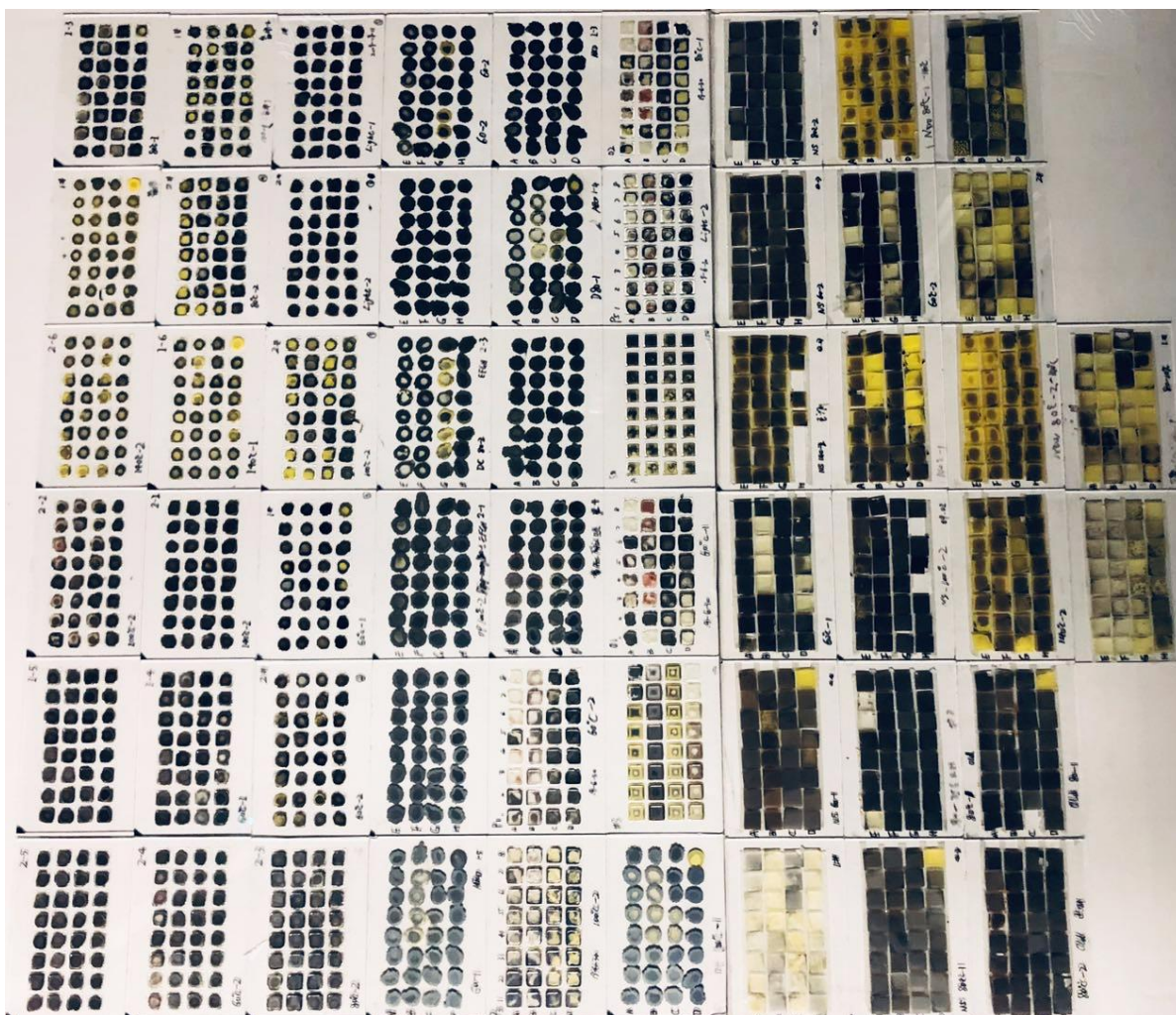
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158 **Supplementary Fig. 4. a-b** XRD patterns of some typical drop-cast samples. XRD patterns of
 159 perovskites with over-stoichiometric doping referred as OST (*e.g.*, excess MAI/CsI) (**a**) and standard
 160 stoichiometric doping referred as SSt (*e.g.*, No. 30: MA_{0.2}FA_{0.8}PbI₃) (**b**). Symbol δ^*/α indicates
 161 δ -FAPbI₃, decomposition product PbI₂, α -FAPbI₃ respectively.

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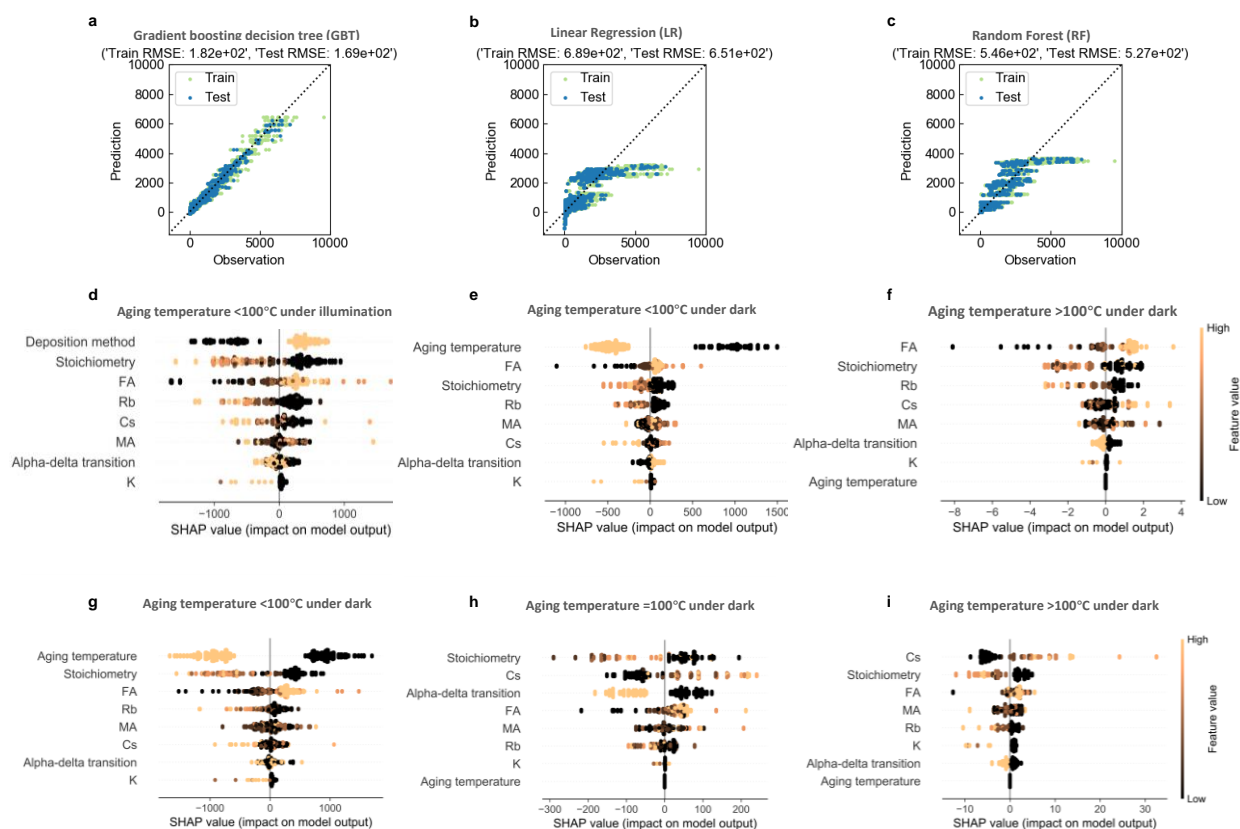


Supplementary Fig. 5. The phase map of the 64 perovskites after storing the samples in a climate chamber with humidity of 30% RH for 5 minutes. The phase map shows that the abilities of Cs doping to stabilize the α phase is stronger than MA. Note that all the samples can maintain the α phase when the humidity is below 25% RH.



Supplementary Fig. 6. Photograph of the samples fabricated *via* the high-throughput robot. The picture was taken after performing the degradation test. Some pixels show a white colour due to the α – δ phase transition.

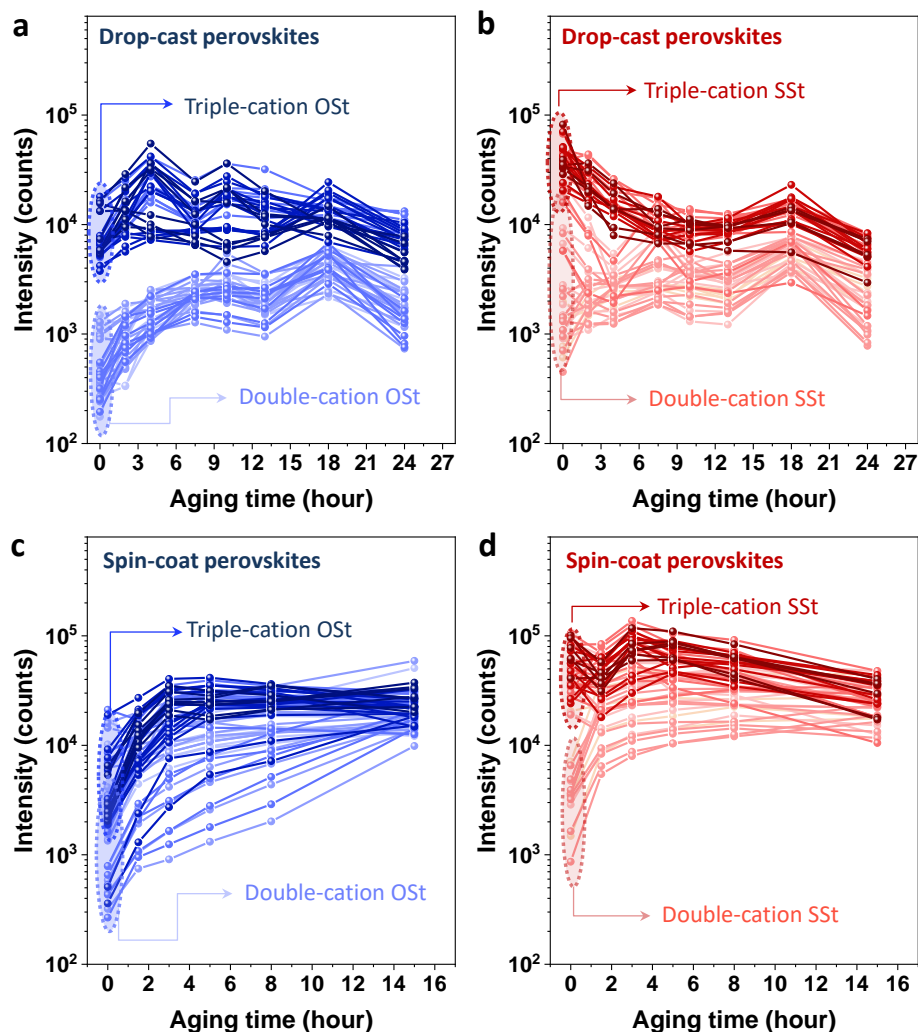
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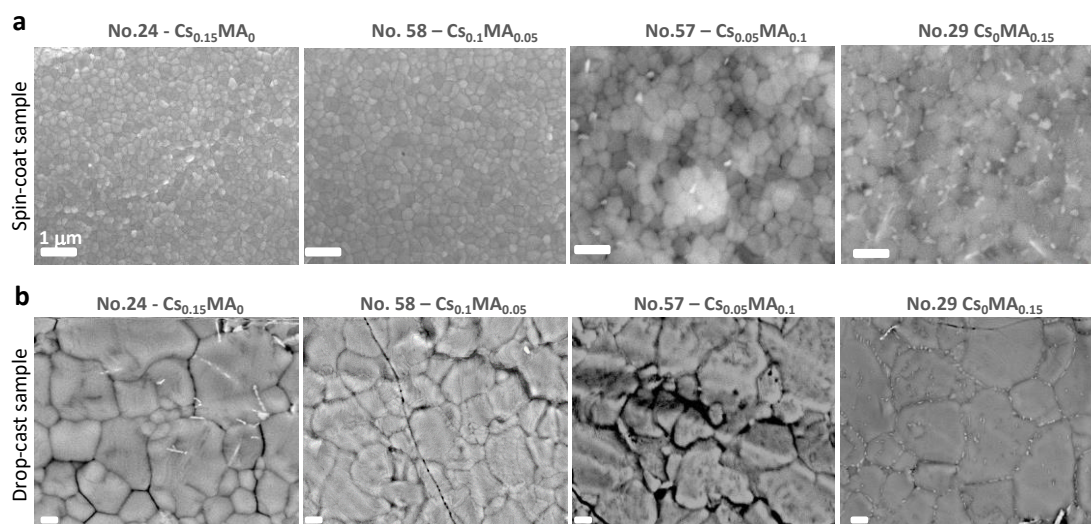
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193 **Supplementary Fig. 7. a-c** The comparison between prediction and observation using GBT regression
 194 (a), LR regression (b) and RF regression (c) with 80%:20% train:test set. **d** The feature importance
 195 ranking based on GBT and SHAP analysis for the T_{80} lifetime of all the samples including spin-coating
 196 and drop-casting under illumination. **e-f** The feature importance ranking based on GBT and SHAP
 197 analysis for spin-coating samples (85°C and 140°C). **g-i** The feature importance ranking based on GBT
 198 and SHAP analysis for drop-casting samples (85°C , 100°C and 140°C). In the figure legend:
 199 Stoichiometry is set as 1 for over-stoichiometric condition (OSt), Deposition_method is set as 1 for
 200 drop-casting method.

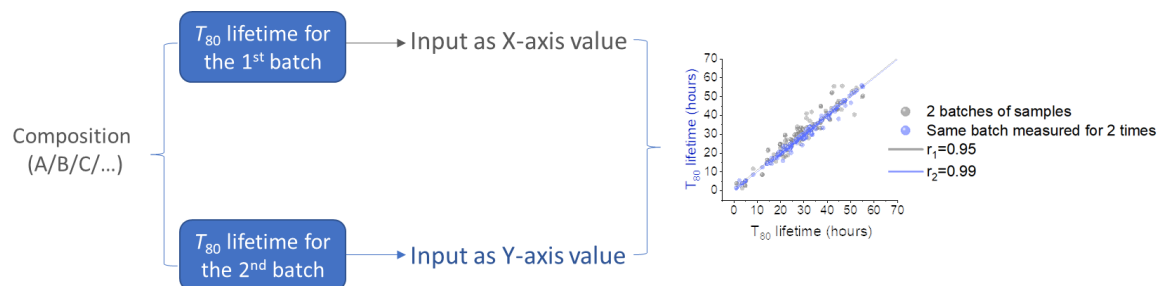
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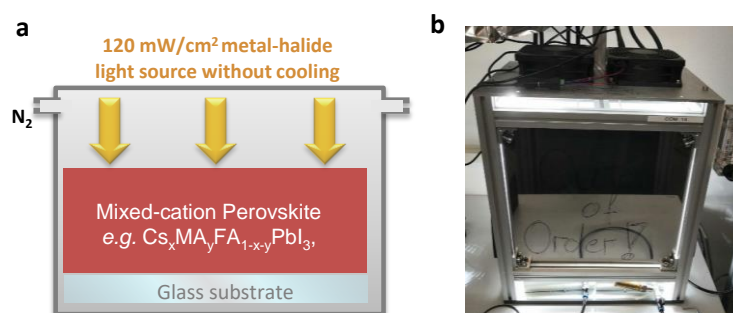
Supplementary Fig. 8. **a-b** PL intensity change with ageing time under 140°C for drop-cast over-stoichiometric perovskites with excess halide salts referred as OST (**a**) and standard-stoichiometric perovskites referred as SSt (**b**); **c-d** for spin-coated OST perovskites with excess halide salts (**c**) and SSt perovskites (**d**). Statistically, the PL intensity of the SSt perovskites is almost one order of magnitude larger than that of SSt samples for both double-cation and triple-cation perovskites. Most perovskites show an initial increase in PL intensity, except for triple-cation perovskites *via the* drop-cast method.



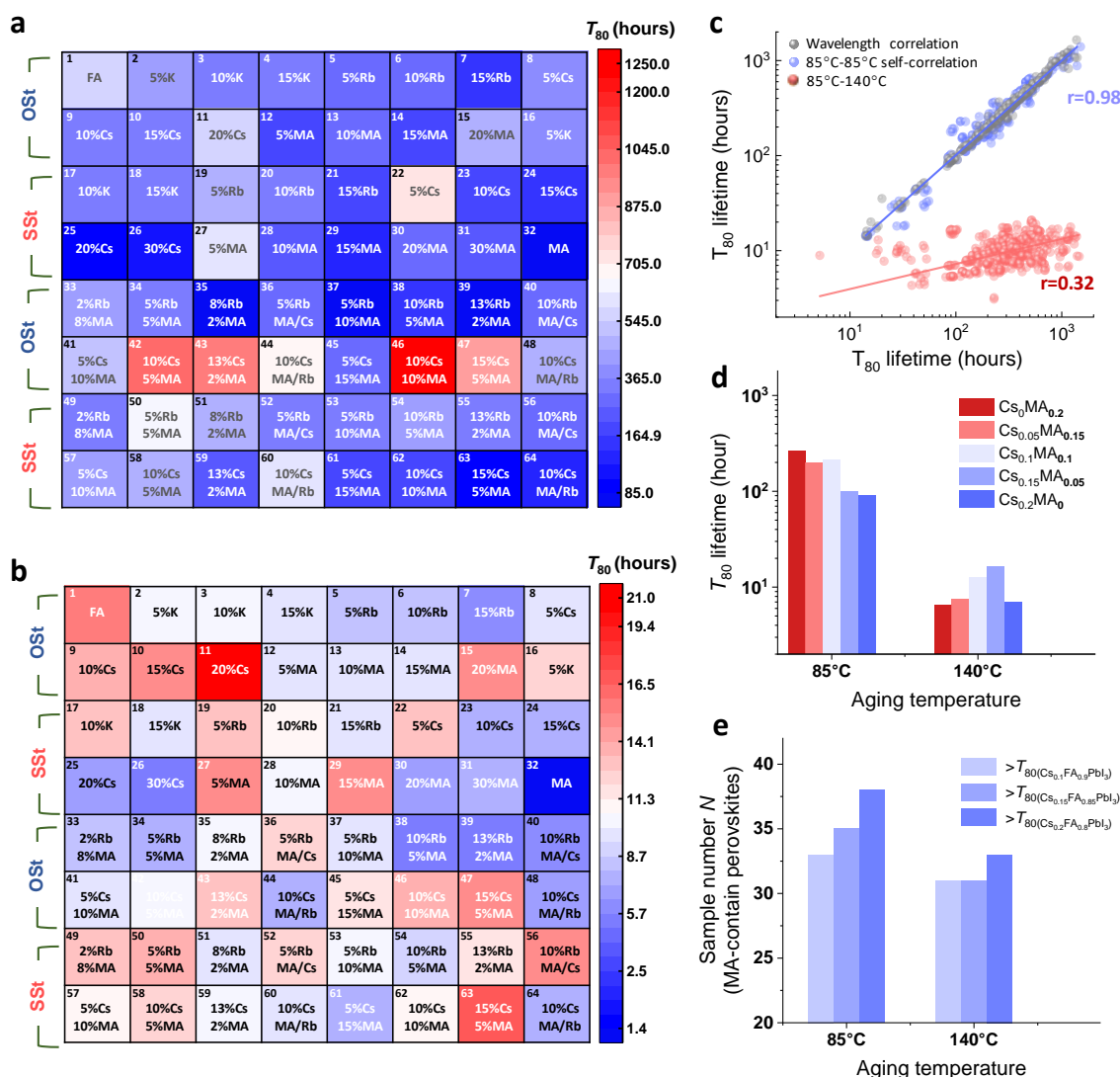
Supplementary Fig. 9. Scanning electron microscopy images of (a) spin-coated samples and (b) drop-cast samples. Scale bar: 1 μm .



Supplementary Fig. 10. Schematic of the self-correlation to validate the reproducibility of the high-throughput system. The self-correlation is defined by correlating T_{80} lifetime of 2 batches of samples with identical compositions, processing and ageing condition.



Supplementary Fig. 11. **a** Schematic of the photostability test. **b** Photograph of the homemade setup equipped with 5 metal halide lamps inside the chamber. The sample box is encapsulated with a glass cover. Fresh N_2 continuously flows through the sample box.



Supplementary Fig. 12. a-b The colour map of the T_{80} lifetime for the 64 spin-coat perovskites with antisovlent quenching, aged in climate chambers preset at 85°C with 10% RH in the dark (**a**) and 140°C with 10% RH in the dark (**b**). **c** The correlation plot of T_{80} at 85 °C against T_{80} at 140 °C. Linear fitting was used to fit all the statistical data to obtain the Pearson correlation coefficients. **d** T_{80} lifetime *versus* ageing temperature for a series of $\text{Cs}_x\text{MA}_{0.2-x}\text{FA}_{0.8}\text{PbI}_3$ perovskites (standard-stoichiometric). **e** The sample counts of MA-containing perovskites that have longer lifetimes than 3 typical MA-free perovskites as a function of ageing temperature.

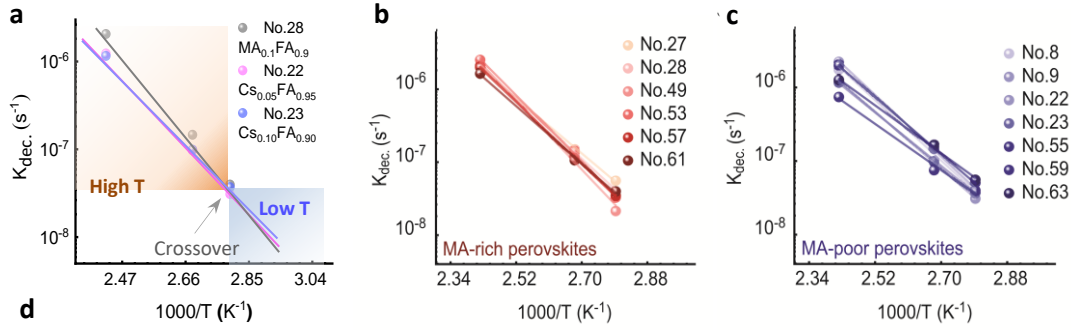
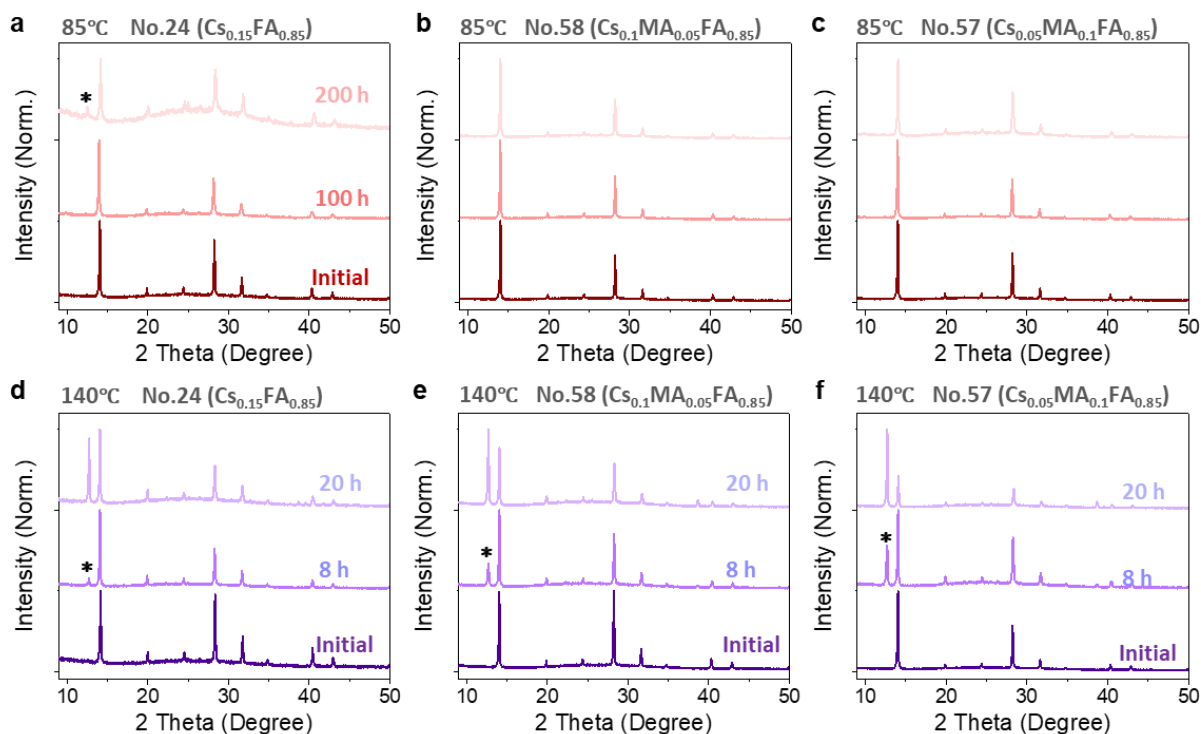


Table : Summary of E_a and rate constant K_0 in decomposition kinetics of perovskite.
In Arrhenius equation: $K=K_0 \exp(-E_a/K_B T)$, where K is the decomposition rate, K_0 is the rate constant, E_a is the activation energy.

Serial Number	Composition	E_a (eV)	$\lg(K_0)$ (s^{-1})
No.1	FAPbI ₃	0.92	5.3
No.32	MAPbI ₃	1.16	9.4
No.27	$MA_{0.05}FA_{0.95}PbI_3$	0.84	4.5
No.28	$MA_{0.1}FA_{0.9}PbI_3$	0.97	5.4
No.49	$MA_{0.08}Rb_{0.02}FA_{0.9}PbI_3$	1.06	7.1
No.53	$MA_{0.1}Rb_{0.05}FA_{0.85}PbI_3$	0.99	6.6
No.57	$MA_{0.1}CS_{0.05}FA_{0.85}PbI_3$	0.96	5.8
No.61	$MA_{0.15}CS_{0.05}FA_{0.8}PbI_3$	0.88	4.8
No.8	FAPbI ₃ (excess 5%CsI)	0.90	5.3
No.9	FAPbI ₃ (excess 10%CsI)	0.92	5.6
No.22	$CS_{0.05}FA_{0.95}PbI_3$	0.86	4.5
No.23	$CS_{0.1}FA_{0.9}PbI_3$	0.79	3.8
No.55	$Rb_{0.13}MA_{0.02}FA_{0.85}PbI_3$	0.85	4.7
No.59	$CS_{0.13}MA_{0.02}FA_{0.85}PbI_3$	0.71	2.3
No.63	$CS_{0.15}MA_{0.05}FA_{0.8}PbI_3$	0.72	2.9

Supplementary Fig. 13. **a** k_{dec} - $1000/T$ plot of No. 28 and No. 22/23 (MA-free perovskites) in logarithmic coordinates, where k_{dec} is the decomposition rate (s^{-1}) and $1000/T$ is the reciprocal of the ageing temperature (K^{-1}). The data are fitted using equation (2). **b-c** k_{dec} - $1000/T$ plot of MA-rich perovskites (MA concentration >5%) and MA-poor perovskites (MA concentration <5%). **d** A summary of the activation energies and pre-exponential factors for some typical MA-rich and Cs/Rb-rich perovskites, obtained by exponentially fitting the data in Fig. 2.

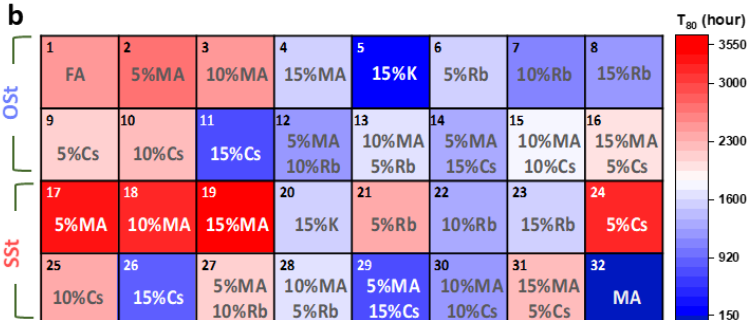


Supplementary Fig. 14. **a-c** XRD patterns of 3 typical perovskites with increasing ageing time at 85°C. **d-f** XRD patterns of 3 typical perovskites with increasing ageing time at 140°C. Symbol ‘*’ indicates PbI₂ in the sample.

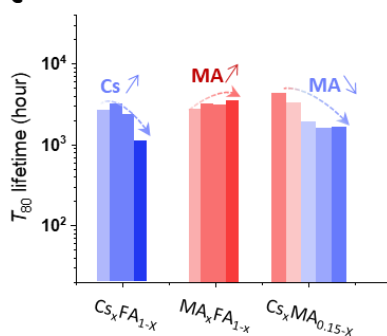
a

Summary of the target composition for the selected 32 spin-coat samples for photo-stability evaluation. Blue and red color indicate doping with overstoichiometry and standard-stoichiometry, respectively							
1	2	3	4	5	6	7	8
FAPbI ₃	MAI-5%	MAI-10%	MAI-15%	KI-15%	RbI-5%	RbI-10%	RbI-15%
9	10	11	12	13	14	15	16
CsI-5%	CsI-10%	CsI-15%	MAI/RbI-5%/10%	MAI/RbI-10%/5%	MAI/CsI-5%/15%	MAI/CsI-10%/10%	MAI/CsI-15%/5%
17	18	19	20	21	22	23	24
MA _{0.05} FA _{0.95} PbI ₃	MA _{0.1} FA _{0.9} PbI ₃	MA _{0.15} FA _{0.85} PbI ₃	K _{0.15} FA _{0.85} PbI ₃	Rb _{0.05} FA _{0.95} PbI ₃	Rb _{0.1} FA _{0.9} PbI ₃	Rb _{0.15} FA _{0.85} PbI ₃	Cs _{0.05} FA _{0.95} PbI ₃
25	26	27	28	29	30	31	32
Cs _{0.1} FA _{0.9} PbI ₃	Cs _{0.15} FA _{0.85} PbI ₃	MA _{0.05} Rb _{0.1} FA _{0.85} PbI ₃	MA _{0.1} Rb _{0.05} FA _{0.85} PbI ₃	MA _{0.05} Cs _{0.15} FA _{0.85} PbI ₃	MA _{0.1} Cs _{0.1} FA _{0.8} PbI ₃	MA _{0.15} Cs _{0.05} FA _{0.8} PbI ₃	MAPbI ₃

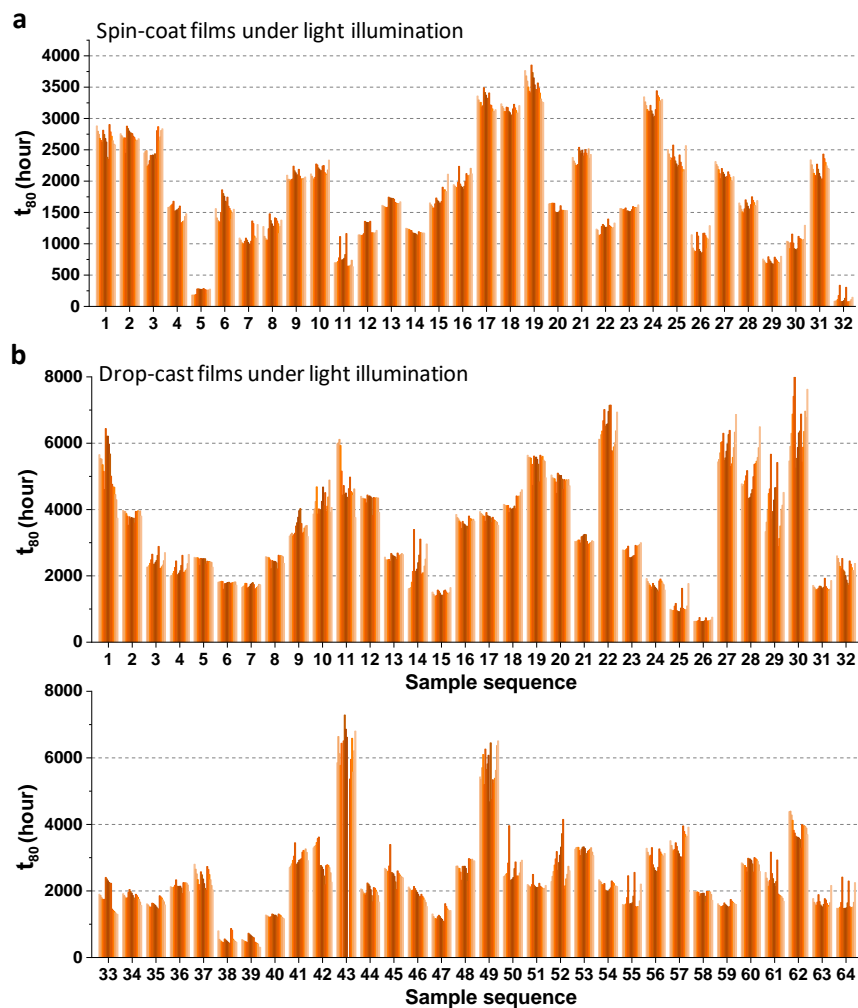
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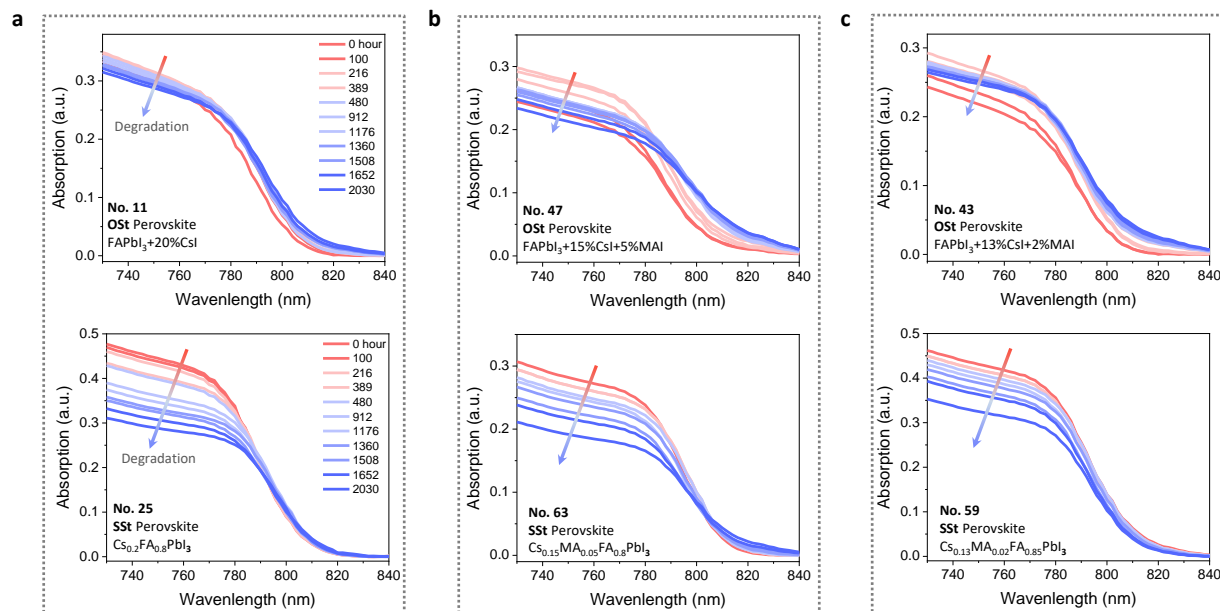
c



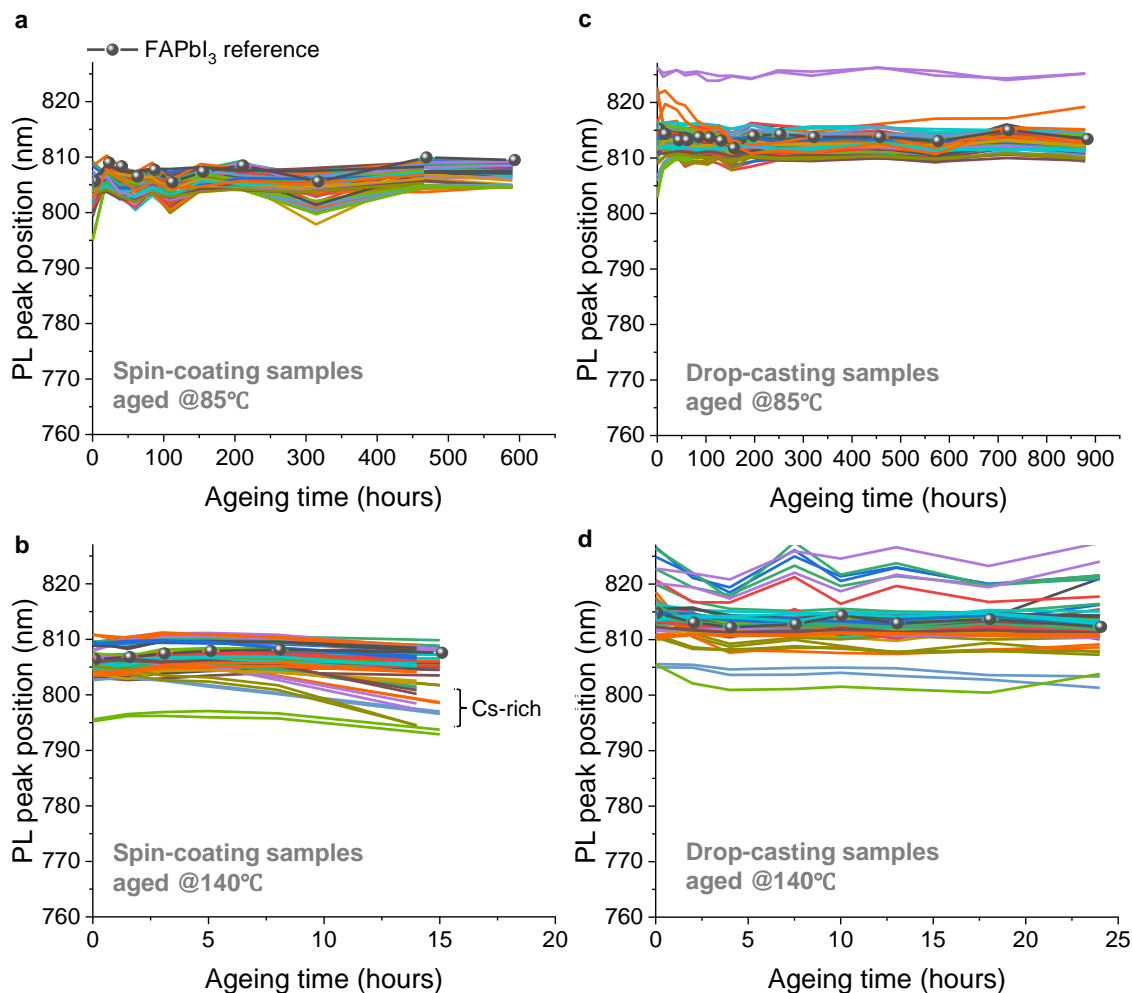
Supplementary Fig. 15. a Summary of the compositions of spin-coated samples selected for the photostability test. **b** The colormap of the T_{80} lifetime for the 32 perovskites under light illumination (metal halide lamp) of 120 mW cm^{-2} intensity at 60°C . **c** T_{80} lifetime of a series of $\text{Cs}_x\text{MA}_y\text{FA}_{1-x-y}\text{PbI}_3$ perovskites under light illumination. For $\text{Cs}_x\text{FA}_{1-x}\text{PbI}_3$ and $\text{MA}_x\text{FA}_{1-x}\text{PbI}_3$, the x values equal 5%, 10%, 15%, 20% and 30% from left to right; for $\text{Cs}_x\text{MA}_{0.15-x}$, the x values equal 0%, 5%, 10%, 13% and 15% from left to right.



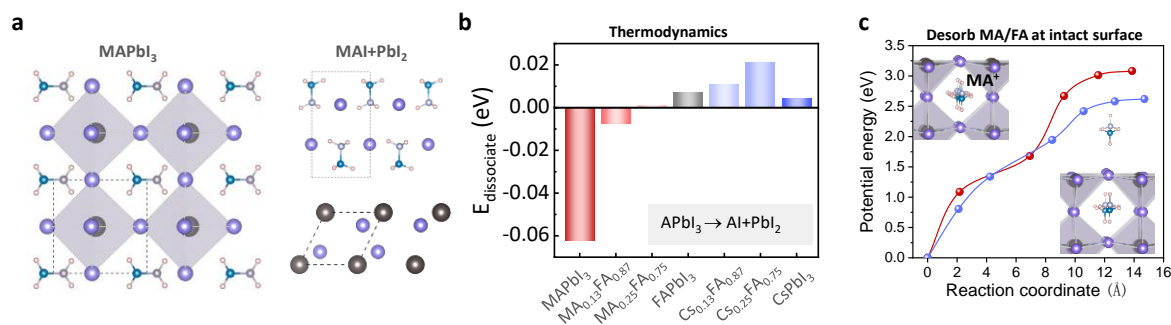
Supplementary Fig. 16. a The histogram of the T_{80} lifetimes for the 32 spin-coated perovskites. **b** The histogram of T_{80} lifetimes of the 64 drop-cast perovskites under light illumination (metal halide lamp) of 120 mW cm^{-2} intensity at 60°C .



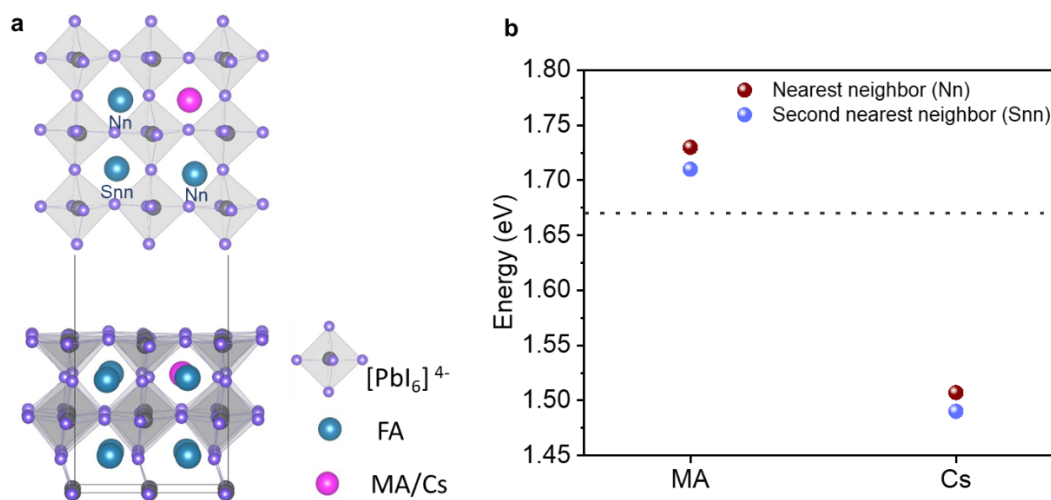
Supplementary Fig. 17. Comparison of the absorption spectra of over-stoichiometric (OSt) perovskites and standard-stoichiometric (SSSt) perovskites during degradation under light illumination. **a** Evolution of the absorption spectra of No. 11 (OSt sample) and No. 25 (SSSt sample); **b** for No. 47 (OSt sample) and No. 63 (SSSt sample); and **c** for No. 43 (OSt sample) and No. 59 (SSSt sample). OSt samples generally present a redshift during degradation, yet this shift is negligible in SSSt samples due to the absence of excess halide salts.



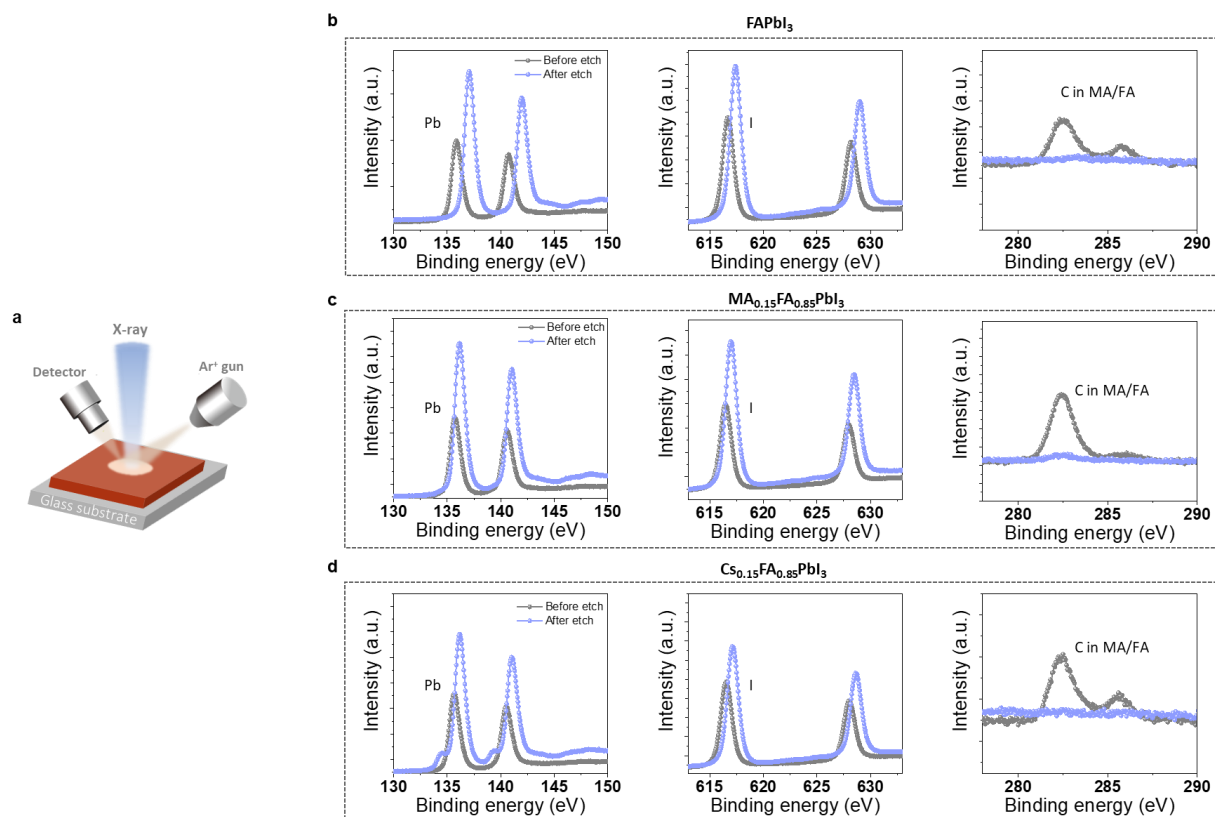
Supplementary Fig. 18. Comparison of the photoluminescence spectra of standard-stoichiometric (SSt) perovskites during degradation. **a-b** Evolution of the PL peak position for spin-coating SSt perovskites, including double-cation and triple-cation perovskites during decomposition process at 85 and 140°C; **c-d** Evolution of the PL peak position for drop-casting SSt perovskites, including double-cation and triple-cation perovskites during decomposition process at 85 and 140°C.



Supplementary Figure 19. **a** The crystal structures of MAPbI₃ and its decomposition products, PbI₂ and MAI. **b** Bar chart of the dissociation energies of FAPbI₃, MAPbI₃, CsPbI₃ and FAPbI₃-based mixed-cation perovskites. **c** The potential energy curve vs. reaction coordinate for the desorption of MA/FA on the intact surface of MAPbI₃/FAPbI₃.

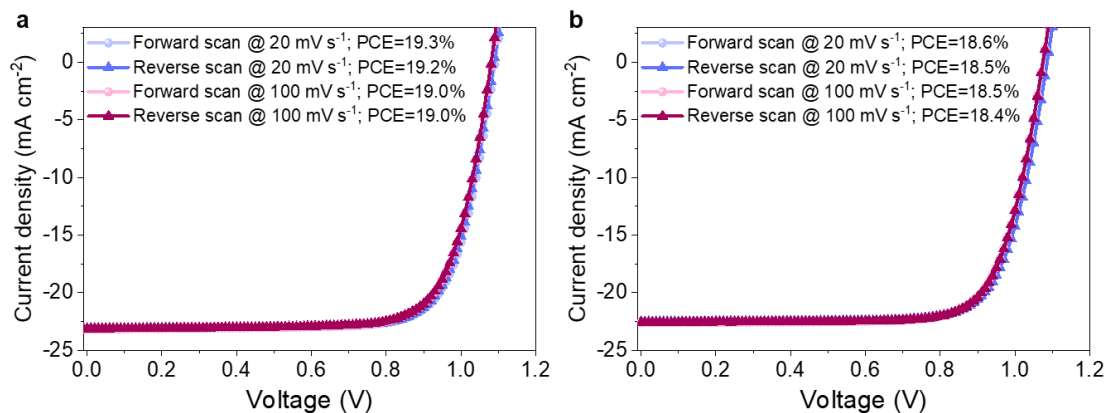


Supplementary Figure 20. **a** The crystal structure of A_{0.13}FA_{0.87}PbI₃ alloy (A = MA, Cs). The FA molecules on the surface can be divided into the nearest neighbor (Nn) and the second nearest neighbor (Snn). **b** Desorption energy of FA molecules at different positions in A_{0.13}FA_{0.87}PbI₃ alloy. The dotted line represents the desorption energy of FA in pristine FAPbI₃ without doping.



Supplementary Figure 21. **a** The schematic diagram of the setup of X-ray photoelectron spectroscopy (XPS) with ion-beam etching. **b** The XPS patterns of FAPbI_3 before and after 10 seconds Ar^+ etching with 2 KV acceleration voltage and 20 uA electron neutralizer. **c** The XPS patterns of $\text{MA}_{0.15}\text{FA}_{0.85}\text{PbI}_3$ before and after 10 seconds Ar^+ etching with above condition. **d** The XPS patterns of $\text{Cs}_{0.15}\text{FA}_{0.85}\text{PbI}_3$ before and after 10 seconds Ar^+ etching with above condition.

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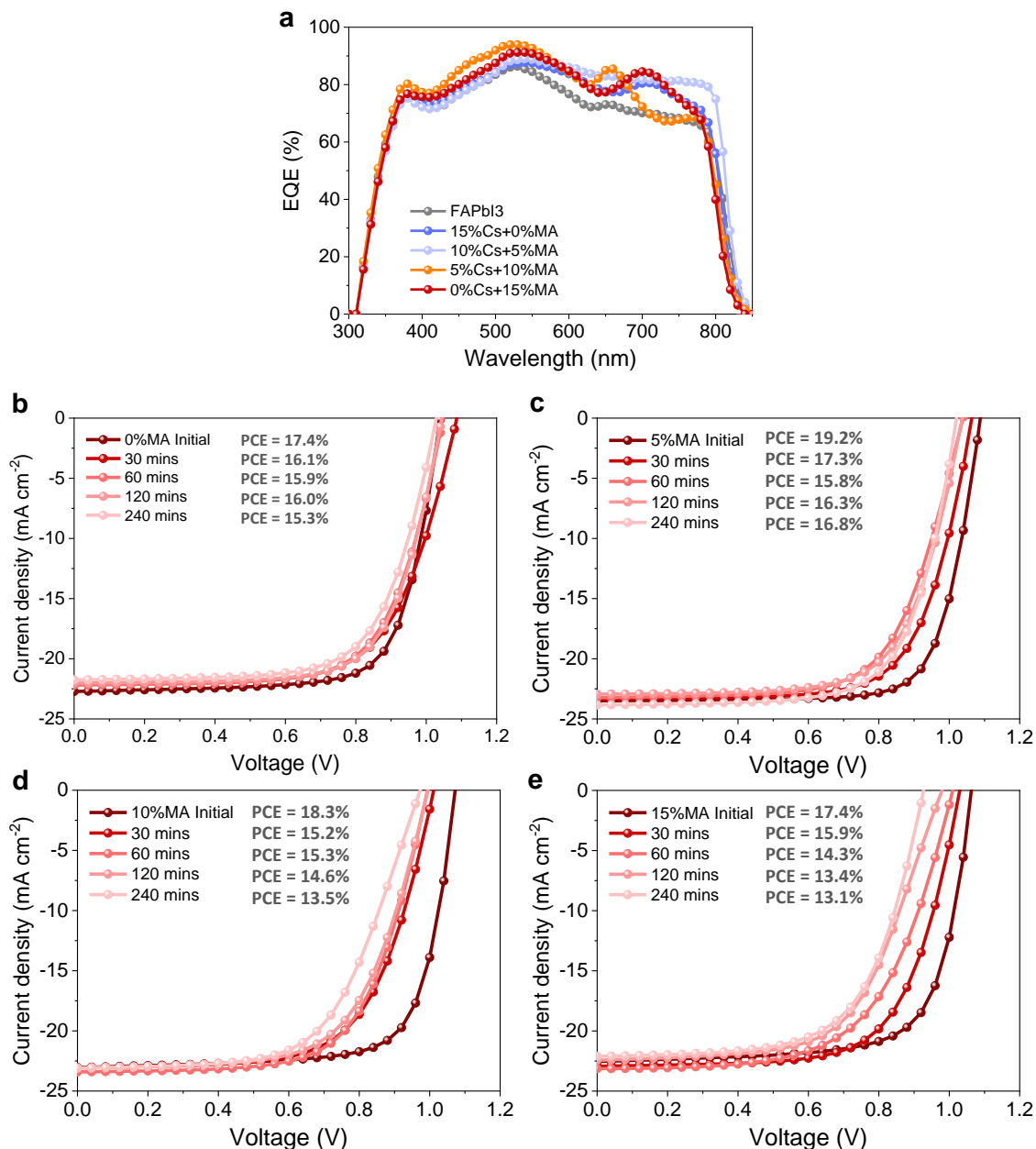


Supplementary Figure 22. Current density-voltage (J - V) curves for $\text{Cs}_{0.1}\text{MA}_{0.05}\text{FA}_{0.85}\text{PbI}_3$ (a) and $\text{Cs}_{0.05}\text{MA}_{0.1}\text{FA}_{0.85}\text{PbI}_3$ (b) perovskite solar cells with forward scan from -0.1 V to 1.2 V and reverse scan from 1.2 V to -0.1 V at different scanning rate.

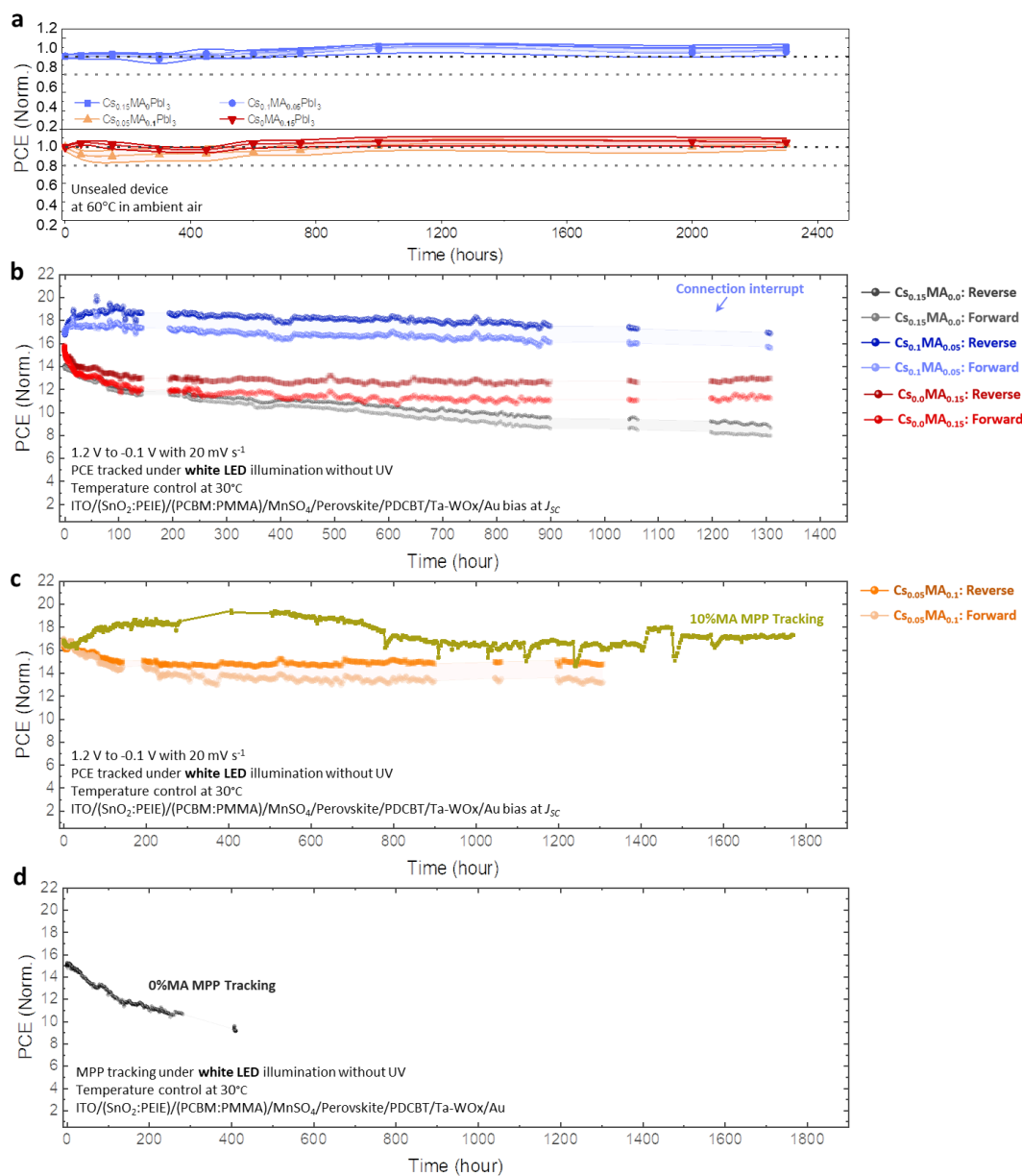
Supplementary Table 3. Report of performance parameter of five typical devices with different compositions

Composition	V_{oc} (V)	J_{sc} (mA cm⁻²)	FF (%)	PCE (%)
FAPbI ₃	1.09	21.7	70	16.6
Cs _{0.15} MA ₀ FA _{0.85} PbI ₃	1.06	22.6	74	17.7
Cs _{0.10} MA _{0.05} FA _{0.85} PbI ₃	1.08	22.9	78	19.3
Cs _{0.05} MA _{0.10} FA _{0.85} PbI ₃	1.07	23.3	76	18.8
Cs ₀ MA _{0.15} FA _{0.85} PbI ₃	1.05	21.9	76	17.4

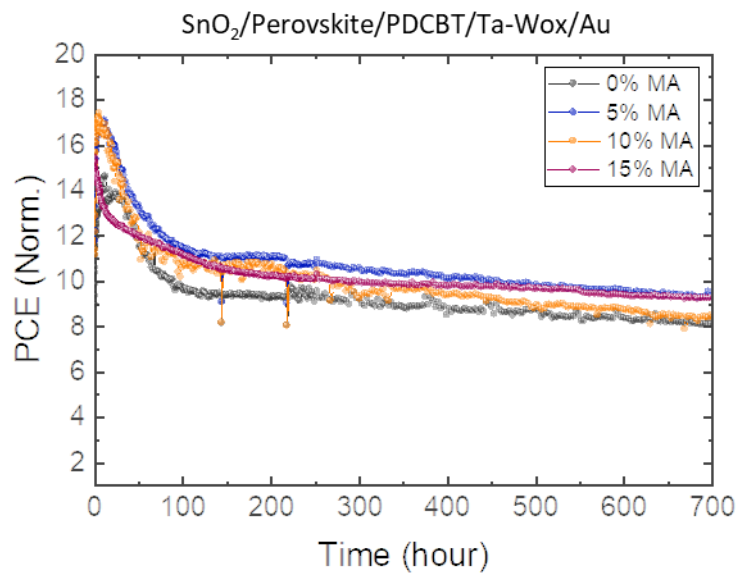
Supplementary Table 3. A summary of the parameter of photovoltaic performance.



Supplementary Figure 23. **a** External quantum efficiency of Cs_xMA_{0.15-x}FA_{0.85}PbI₃ perovskite solar cells with integrated current density of 20.7/21.8/22.8/21.9/21.8 mA cm⁻² for FAPbI₃/0%MA/5%MA/10%MA/15%MA respectively. **b-e** Current density-voltage (*J-V*) curves for Cs_xMA_{0.15-x}FA_{0.85}PbI₃ perovskite solar cells aged at 140°C for different times, measured with a scanning rate of 20 mV s⁻¹ from -0.1 to 1.2 V. (A) *x*=0, 0.05, 0.1, and 0.15 are denoted as 0% MA (**b**), 5% MA (**c**), 10% MA (**d**), and 15% MA (**e**), respectively. The devices are aged at 140°C before deposition of the hole transporting layer.



Supplementary Figure 24. a Statistical PCE change during the ageing process at 60°C in ambient air. The humidity was approximately 35% RH. **b** Long-term stability of $\text{Cs}_x\text{MA}_{0.15-x}\text{FA}_{0.85}\text{PbI}_3$ ($x=0, 5\%$, and 15%) perovskite solar cells tested under 100 mW cm^{-2} white LED illumination. For each sample, the efficiency was recorded at a scanning rate of 20 mV s^{-1} from 1.2 to -0.1 V as the reverse scan and from -0.1 V to 1.2 V as the forward scan. **c** Long-term stability for $x=10\%$ with MPP tracking. **d** Long-term stability for $x=0\%$ with MPP tracking. The efficiency value is based on the stabilized efficiency biased at the maximum power point.



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 345 **Supplementary Figure 25.** Long-term stability of $\text{Cs}_x\text{MA}_{0.15-x}\text{FA}_{0.85}\text{PbI}_3$ ($x=0\%$, 5% , 10% and 15%)
 346 perovskite solar cells with device structure of $\text{SnO}_2/\text{Perovskite}/\text{PDCBT}/\text{Ta-WO}_x/\text{Au}$, under 100 mW cm^{-2}
 347 white LED illumination. The efficiency was recorded at a scanning rate of 20 mV s^{-1} from 1.2 to -0.1 V .

348 **Supplementary Table 4.** A summary of previous studies on the device stability of mixed-cation
 349 perovskite solar cells.

Supplementary Table 4: Summary of device stability on perovskites (MA⁺: CH₃NH₃⁺; FA⁺: NH₂CHNH₂⁺)

Aging condition	Composition and processing	Conclusion	Reference
85°C-light in N ₂	Rb _{0.05} (Cs _{0.05} MAFA) _{0.95} Pb(I _{0.83} Br _{0.17}) ₃ -based devices <i>via</i> 1-step spin-coating	MA-containing 5% loss after 500 hours	Science 354, 206-209 (2016).
30°C-light in N ₂	Cs _x (MA _{0.17} FA _{0.83}) _(100-x) Pb(I _{0.83} Br _{0.17}) ₃ (x=0/10)-based devices <i>via</i> 1-step spin-coating	MA-containing 10% loss after 250 hours	Energy Environ. Sci. 9, 1989-199 (2016)
30°C-light with N ₂ flow	Cs _x (MA _{0.17} FA _{0.83}) _(100-x) Pb(I _{0.97} Br _{0.03}) ₃ (x=0/1/2/3) devices <i>via</i> 2-step spin-coating	MA-containing 40% loss after 400 hours	Nat. Commun. 9, 1607 (2018)
25°C-light in air (humidity: 40%RH)	MA _{0.15} FA _{0.85} Pb(I _{0.85} Br _{0.15}) ₃ -based devices with excess 5 mol.% RbI <i>via</i> 1-step spin-coating	MA-containing 0% loss after 100 hours	Nano Energy 30, 330–340 (2016)
30°C-light in air (humidity not indicated)	(5-AVA) _x (MA) _{1-x} PbI ₃ -based devices <i>via</i> doctor-blading	MA-containing 0% loss after 1000 hours	Science 345, 295-298 (2014)
30°C-light in N ₂	(FAPbI ₃) _{0.95} (MAPbBr ₃) _{0.05} -based devices <i>via</i> 1-step spin-coating	MA-containing 5% loss after 1400 hours	Nature 567, 511–515 (2019)
25°C in air under dark	FA _{0.15} MA _{0.85} PbI ₃ -based devices <i>via</i> 2-step spin-coating and thermal evaporation	MA-containing 3% loss after 800 hours	Nat. Energy, 4: 150 (2019)
85°C-dark in N ₂	MAPbI ₃ -based devices <i>via</i> 1-step spin-coating	MA-containing 5% loss after 500 hours	Nat. Commun. 10: 1161 (2019)
30°C-light in N ₂	MAPbI ₃ -based devices <i>via</i> 1-step spin-coating	MA-containing 3% loss after 500 hours	Nat. Commun. 10: 1161 (2019)
65°C-light in N ₂	Cs _{0.05} MA _{0.14} FA _{0.81} PbI _{2.55} Br _{0.45} -based devices <i>via</i> 1-step spin-coating	MA-containing 3% loss after 1200 hours	Science 365, 473–478 (2019)
85°C-dark in air	FA _{0.83} Cs _{0.17} Pb(I _{0.83} Br _{0.17}) ₃ -based devices <i>via</i> 1-step spin-coating	MA-free 25% efficiency loss after 3 hours	Adv. Fun. Mater. 29, 1900466 (2019)
30°C-light in N ₂	Rb ₅ Cs ₁₀ FAPbI ₃ -based devices <i>via</i> 1-step spin-coating	MA-free 22% loss after 1000h and 6% loss with surface passivation	Science 362, 449–453 (2018)
35°C-light in N ₂	Cs _{0.17} FA _{0.83} Pb(Br _{0.17} I _{0.83}) ₃ -based devices <i>via</i> 1-step spin-coating	MA-free 15% efficiency loss after 600 hours	Nat. Energy 5, 35-49 (2020)
25°C-light in N ₂	Cs _{0.925} K _{0.075} PbI ₂ Br	MA-free 20% efficiency loss after 120 hours	Nano Lett. 17, 2028-2033 (2017)
60°C-light in N ₂	Cs _{0.1} FA _{0.9} PbI ₃	MA-free 30% efficiency loss after 220 hours	Adv. Energy Mater. 5, 1501310 (2015)
60°C-light in air	Cs _{0.17} FA _{0.83} Pb(Br _{0.4} I _{0.6}) ₃	MA-free 20% efficiency loss after 1000 hours	Nat. Energy 2, 17135 (2017)